Specifications

Products Name	Low Resistance Chip Resistor	
Product Series	FLRH11050W*R***F	
Classification	Generic Specification	



FLRH11050W Low Resistance Chip Resistor Specification

1. Scope

This specification applies to FLRH11050W Series Low Resistance Chip Resistor for use in electric equipment.

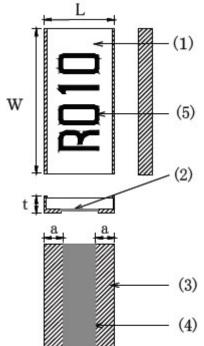
2. Part number

<u>FLR</u>	<u>H11050</u>	<u>W</u>	*	<u>R***</u>	E
(1)	(2)	(3)	(4)	(5)	(6)
 (1) Product series (2) Size (3) Electrode type (4) Characteristic type 			Foil Low Resistance H11050: Long-side electrode 11.0*5.0mm size Wrap-up type C: High operating temperature type M: Low thermoelectric power type		
(5) Nominal resistance(6) Resistance tolerance			(example) 10mΩ → R010 F (±1.0%) G(±2.0%) J(±5.0%)		

3. Structure

The ceramic substrate is adhered to the metal foil (Ni-Cu) resistive element; terminals are formed on top of the foil.

4. Dimensions



No.	Components	Material / Process
(1)	Substrate	Alumina 96%
(2)	Resistor	Ni-Cu alloy
(3)	Terminals	Plated Sn+Ni (on Cu)
(4)	Protection coat	Epoxy resin (Green)
(5)	Marking	Epoxy resin (Black)

Symbol	Dimensions (mm)		
L	5.00±0.20		
W	11.00±0.20		
а	2mΩ~:0.80±0.20 1mΩ:1.60±0.20		
t	0.50±0.20		

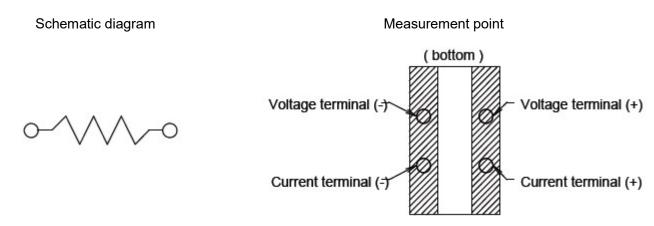
5. Marking

Resistance value code is marked on the top surface.

Example)	10mΩ	-> R010
	20mQ	-> R020

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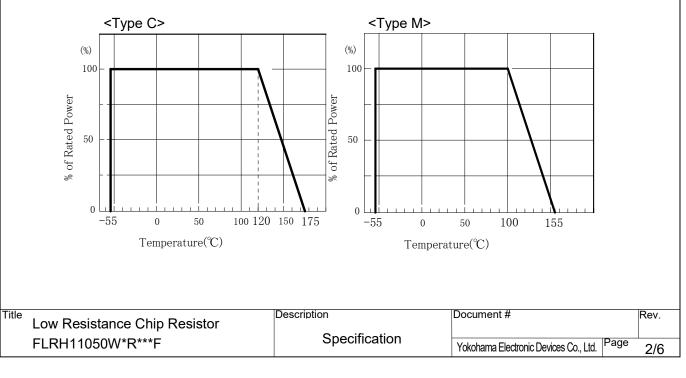
6. Schematic diagram, Measurement point



7. Specification

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Parameter	Specification		
Resistance Value	1m to 500m Ω (for standard resistances)		
Resistance Tolerance	F (±1.0%) for 3m Ω~		
Temperature Coefficient of Resistance	±50ppm/°C for 3mΩ~		
Rated Load	6.0W		
Operating Temperature Range	Type C: -55~+175°C, Type M: -55~+155°C	Refer to Figure-1	
Rated ambient temperature	Type C: +120°C, Type M: +100°C	i iguie-i	
Rated Voltage	√ (Power×Resistance) (V)		
Maximum Over Current	when $\leq 10 \text{m} \Omega$: which smaller between $\sqrt{600W \div \text{resistance}}$ 10msec on, 60sec off in maximum of 10 times with recommended footprint set forth hereunder	,	
	When $>10m \Omega$ & $<100m \Omega$: which smaller between $\sqrt{440W \div resistance}$ 10msec on, 60sec off in maximum of 10 times with recommended footprint set forth hereunde		

Fighure-1 Derating Curve



8. Reliability testing

Test Item	Test Condition	Specification			
Short Time Over Load	Voltage of 1.5 times the rated voltag	±(1.0%+0.0005Ω)			
Load life	Rated voltage for 90 min followed by at a temperature of 70±3°C. Cycles shall be repeated for 1000h.	±(2.0%+0.0005Ω)			
Moisture Load life	Rated voltage for 90 min followed by at a temperature of 60±2°C with rela Cycles shall be repeated for 1000h.	±(2.0%+0.0005Ω)			
Temperature	[-55°C 30 min -> R.T. 3 min ->	100 continuous cycles	±(1.0%+0.0005Ω)		
Ċycle	+155°C 30 min -> R.T. 3 min]	1000 continuous cycle	±(2.0% +0.0005Ω)		
Soldering Hearting	260±5°C solder, 10±1sec dip	±(1.0%+0.0005Ω)			
Substrate Bending	Test board length: 90mm Bend depth: 2mm Test board: Glass-Epoxy t=1.6mm	±(1.0%+0.0005Ω)			
Solderability	245±5°C solder, 3+1/-0 sec dip.	A new solder shall cover minimum of 90%			

9. Packaging

Packing quantity: 1,000 pieces/r	eel.
Tape diagram/dimension	Figure-2
Peeling strength of seal tape	Figure-3
Reel form Labeling position	Figure-4
Taping direction	Figure-5

Marking The following items shall be printed on the reel label. (Figure-6)

Part number

Quantity for each reel

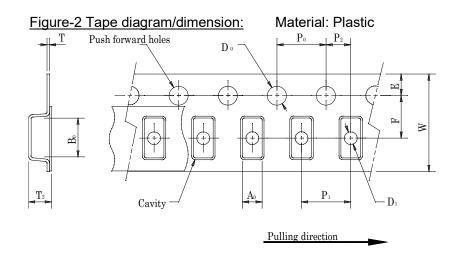
Manufacturing month code

Manufacturer

Inspection number (Lot number)

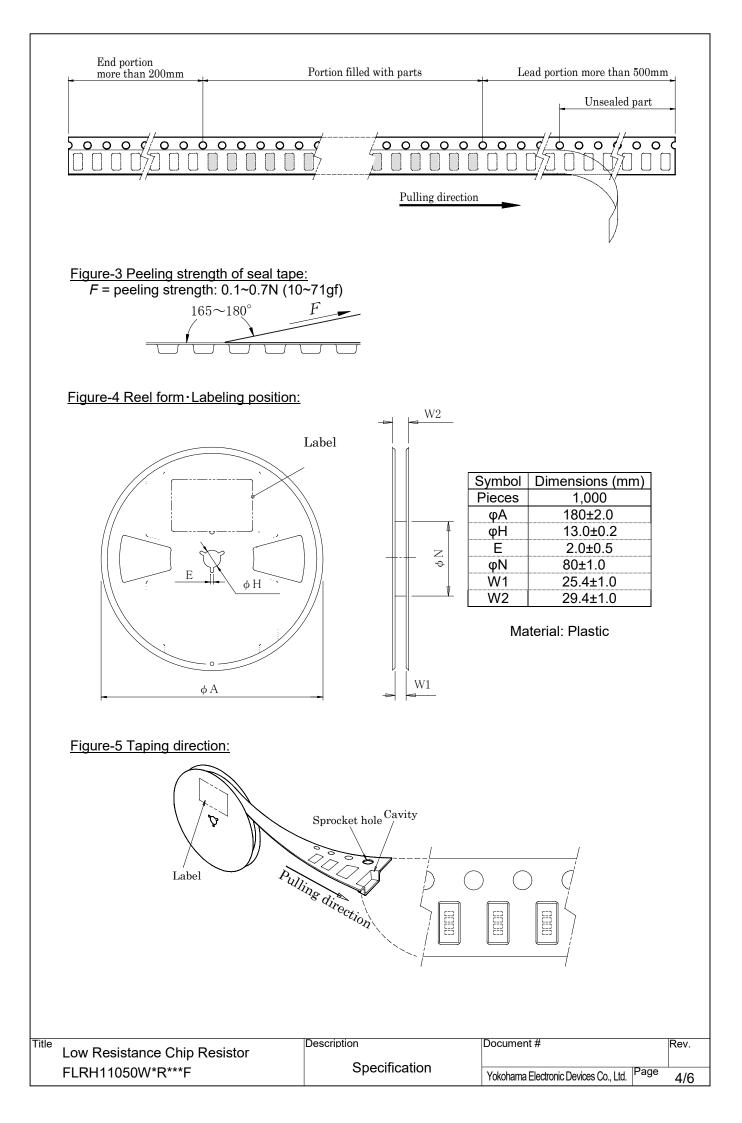
The country of origin

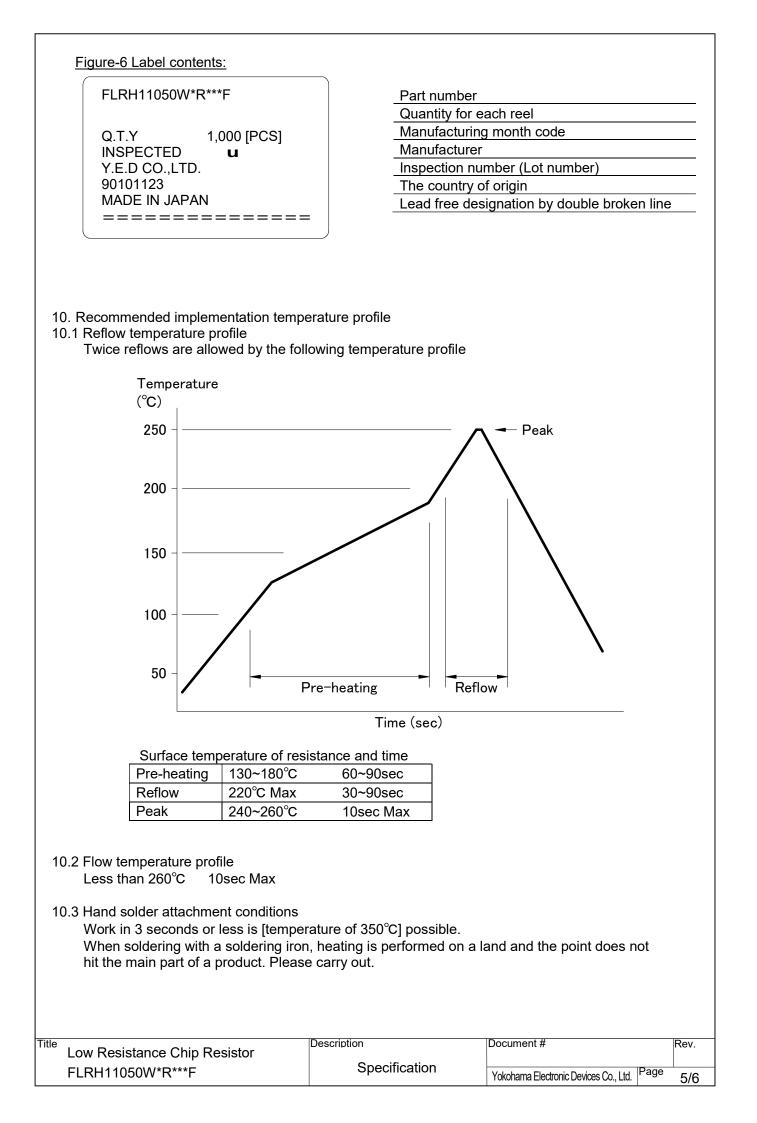
Lead free designation by double broken line



Symbol Dimensions (mm	
A0	5.40±0.10
B0	11.50±0.10
W	24.00±0.30
F	11.50±0.10
E	1.75±0.10
P0	4.00±0.10
P1	8.00±0.10
P2	2.00±0.10
D0	1.50±0.10
D1	1.50±0.10
Т	0.30±0.05
T2	1.20±0.15

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 Recommended land pattern (for curre Board materials: Glass epoxy (FR-4) Thickness of copper foil: 100 um Note: The terminal temperature should 	t=0.6mm	ted power.
h \	c Symbol c a b c c c a b c c	Dimensions (mm) 2mΩ~:3.60 1mΩ:1.80 5.60 11.20
12. Country of origin and Location Country of origin:Japan Location:Yokohama Electro Address:Shin-Yokohama, K	nic Devices Co.,Ltd. íouhoku-Ku, Yokohama-city,	222-0033 Japan
 Storage note To maintain good solderability, Store to Temperature: 5~35°C Humidity: 45~88 Store the components at the place avoid chloride, sulfurous acid gas and hydro Store the components at the place avoid store the components at t	5% RH oiding moisture, dust and co ogen sulfide) that may cause	rrosive harmful gas (hydrogen
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